



ES1A THRU ES1J

1.0 AMP. Super Fast Surface Mount Rectifiers



Voltage Range
50 to 600 Volts
Current
1.0 Ampere

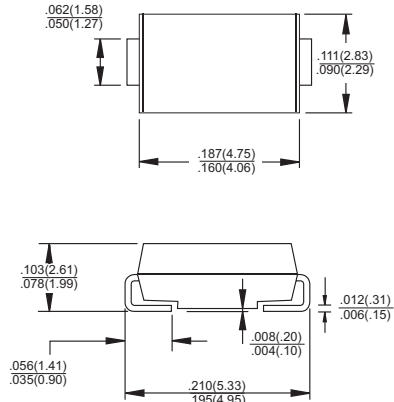
Features

- ✧ Glass passivated junction chip
- ✧ For surface mounted application
- ✧ Low profile package
- ✧ Built-in strain relief,
- ✧ Ideal for automated placement
- ✧ Easy pick and place
- ✧ Superfast recovery time for high efficiency
- ✧ Glass passivated chip junction
- ✧ High temperature soldering:
260°C/10 seconds at terminals
- ✧ Plastic material used carries Underwriters
Laboratory Classification 94V-O

Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Terminals: Solder plated
- ✧ Polarity: Indicated by cathode band
- ✧ Packing: 12mm tape per E1A STD RS-481
- ✧ Weight: 0.064 gram

SMA/DO-214AC



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	ES 1A	ES 1B	ES 1C	ES 1D	ES 1F	ES 1G	ES 1H	ES 1J	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V _{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current See Fig. 1	I _(AV)	1.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	30								A
Maximum Instantaneous Forward Voltage @ 1.0A	V _F	0.95				1.3		1.7		V
Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =100°C	I _R	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	T _{rr}	35								nS
Typical Junction Capacitance (Note 2)	C _j	10				8				pF
Maximum Thermal Resistance (Note 3)	R _{θJA} R _{θJL}	85 35								°C/W
Operating Temperature Range	T _J	-55 to +150								°C
Storage Temperature Range	T _{STG}	-55 to + 150								°C

Notes: 1. Reverse Recovery Test Conditions: $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$

2. Measured at 1 MHz and Applied $V_R = 4.0\text{ Volts}$

3. P.C.B. Mounted on 0.2×0.2 " (5 x 5mm) Copper Pad Area.

RATINGS AND CHARACTERISTIC CURVES (ES1A THRU ES1J)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

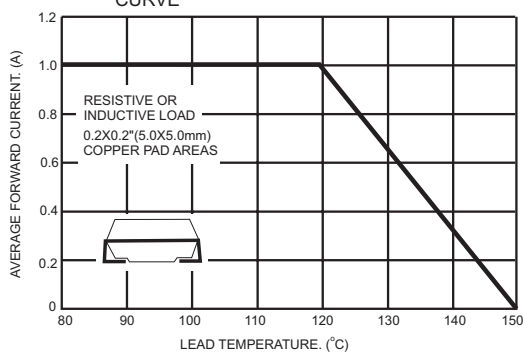


FIG.2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

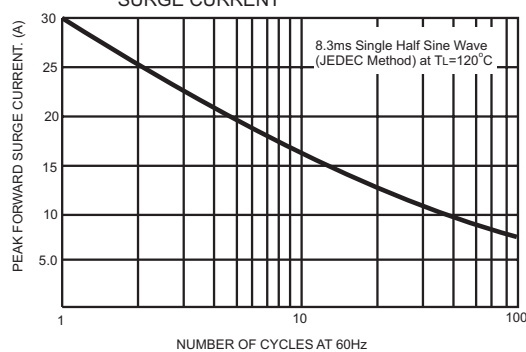


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

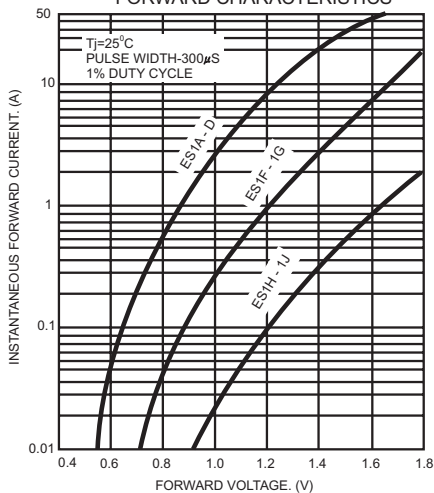


FIG.4- TYPICAL REVERSE CHARACTERISTICS

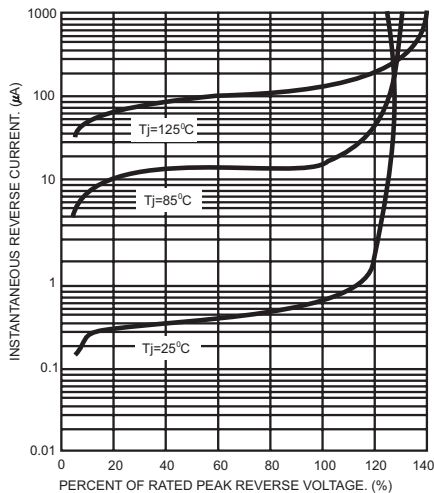


FIG.5- TYPICAL JUNCTION CAPACITANCE

